INA185 26-V, 350-kHz, Bidirectional, High-Precision Current Sense Amplifier in Ultra-Small (SOT-563) Package

1 Features

- SC70 and SOT-563 packages
  - SC70 offers compatibility to existing solutions
  - SOT-563 is 39% smaller footprint than SC70
  - SOT-563 dimensions is 1.6 mm × 1.6 mm × 0.55 mm
- Common-mode range (V_{CM}): –0.2 V to +26 V
- High bandwidth: 350 kHz (A1 devices)
- Offset voltage:
  - ±55 µV (maximum) at V_{CM} = 0 V
  - ±100 µV (maximum) at V_{CM} = 12 V (A4 device)
- Output slew rate: 2 V/µs
- Bidirectional current-sensing capability
- Accuracy:
  - Maximum gain error (A1, A2, A3): ±0.2%
  - Maximum offset drift: 0.5 µV/°C
- Gain options:
  - 20 V/V (A1 devices)
  - 50 V/V (A2 devices)
  - 100 V/V (A3 devices)
  - 200 V/V (A4 devices)
- Quiescent current: 260 µA (maximum)

2 Applications

- Motor control
- Battery monitors and balancers
- Power management
- Lighting control
- Solar inverters

3 Description

The INA185 current sense amplifier is designed for use in cost-sensitive space constrained applications. This device is a bidirectional, current-sense amplifier (also called a current-shunt monitor) that senses the voltage drop across a current-sense resistor at common-mode voltages from –0.2 V to +26 V, independent of the supply voltage. The INA185 integrates a matched resistor gain network in four, fixed-gain device options: 20 V/V, 50 V/V, 100 V/V, or 200 V/V. This matched gain resistor network minimizes gain error and reduces the temperature drift.

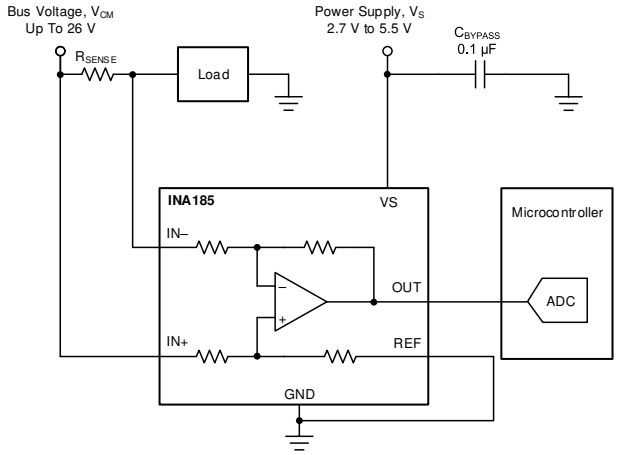
The INA185 operates from a single 2.7-V to 5.5-V power supply. The device draws a maximum supply current of 260 µA and features high slew rate and bandwidth making this device an excellent choice for many power-supply and motor-control applications.

The INA185 is available in an industry standard SC70 package and low profile 6-pin, SOT-563 package. The SOT-563 package has a body size of size of only 2.56 mm^2, including the device pins. All device options are specified over the extended operating temperature range of –40°C to +125°C.

Package Information

PART NUMBER	PACKAGE(1)	PACKAGE SIZE(2)
INA185	DRL (SOT-563, 6)	1.60 mm × 1.60 mm
	DCK (SC70, 6)	2.00 mm × 2.10 mm

(1) For all available packages, see Section 10.
(2) The package size (length × width) is a nominal value and includes pins, where applicable.



Typical Application Circuit

An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.

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4 Pin Configuration and Functions

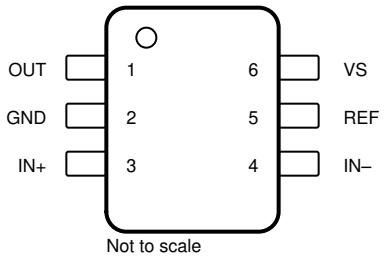


Figure 4-1. INA185: DRL Package 6-Pin SOT-563 Top View

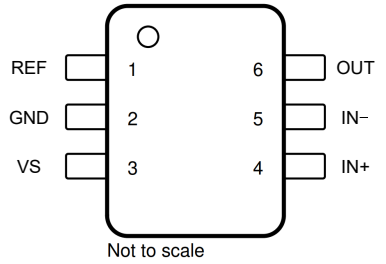


Figure 4-2. INA185: DCK Package 6-Pin SC70 Top View

Table 4-1. Pin Functions

PIN			TYPE	DESCRIPTION
NAME	SOT-563	SC70		
GND	2	2	Analog	Ground
IN–	4	5	Analog input	Current-sense amplifier negative input. For high-side applications, connect to load side of sense resistor. For low-side applications, connect to ground side of sense resistor.
IN+	3	4	Analog input	Current-sense amplifier positive input. For high-side applications, connect to bus-voltage side of sense resistor. For low-side applications, connect to load side of sense resistor.
OUT	1	6	Analog output	Output voltage
REF	5	1	Analog input	Reference input
VS	6	3	Analog	Power supply, 2.7 V to 5.5 V

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5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V_S	Supply voltage			6	V
	Analog inputs, IN+, IN–(2)	Differential (V_{IN+}) – ($V_{IN–}$)	–26	26	V
		Common-mode(3)	GND – 0.3	26	
V_{REF}	Reference voltage		GND – 0.3	V_S + 0.3	V
V_{OUT}	Output voltage(3)		GND – 0.3	V_S + 0.3	V
T_A	Operating temperature		–55	150	°C
T_J	Junction temperature			150	°C
T_{stg}	Storage temperature		–65	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) V_{IN+} and $V_{IN–}$ are the voltages at the IN+ and IN– pins, respectively.
(3) Input voltage at any pin can exceed the voltage shown if the current at that pin is limited to 5 mA.

5.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001(1)	±3000	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101(2)	±1000	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V_{CM}	Common-mode input voltage	-0.2	12	26	V
V_S	Operating supply voltage	2.7	5	5.5	V
T_A	Operating free-air temperature	–40		125	°C

5.4 Thermal Information

THERMAL METRIC(1)		INA185		UNIT
		DCK (SC70)	DRL (SOT-563)	
		6 PINS	6 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	188.0	230.9	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	140.8	94.1	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	78.8	112.8	°C/W
ψ_{JT}	Junction-to-top characterization parameter	62.1	3.8	°C/W
ψ_{JB}	Junction-to-board characterization parameter	78.5	112.1	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	N/A	N/A	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics application report*.

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5.5 Electrical Characteristics

at T_A = 25°C, V_{SENSE} = V_{IN+} – $V_{IN–}$, V_S = 5 V, V_{REF} = V_S / 2, and V_{IN+} = 12 V (unless otherwise noted)

PARAMETER		CONDITIONS		MIN	TYP	MAX	UNIT
INPUT							
CMRR	Common-mode rejection ratio, RTI (1)	V_{IN+} = 0 V to 26 V, V_{SENSE} = 0 mV, T_A = –40°C to +125°C	A1 device	86	100		dB
			A2, A3 devices	96	100		
			A4 devices	106	120		
V_{OS}	Offset voltage, RTI	V_{SENSE} = 0 mV, V_{IN+} = 0 V	A1 devices		±25	±135	µV
			A2, A3, A4 devices		±5	±55	
		V_{SENSE} = 0 mV, V_{IN+} = 12 V	A1 devices		±100	±450	
			A2, A3 devices		±25	±130	
			A4 device		±25	±100	
dV_{OS}/dT	Offset drift, RTI	V_{SENSE} = 0 mV, T_A = –40°C to +125°C			0.2	0.5	µV/°C
PSRR	Power supply rejection ratio, RTI	V_S = 2.7 V to 5.5 V, V_{IN+} = 12 V, V_{SENSE} = 0 mV			±8	±30	µV/V
I_{IB}	Input bias current	V_{SENSE} = 0 mV, V_{CM} = 0 V			-6		µA
		V_{SENSE} = 0 mV			75		
I_{IO}	Input offset current	V_{SENSE} = 0 mV			±0.05		µA
OUTPUT							
G	Gain		A1 devices		20		V/V
			A2 devices		50		
			A3 devices		100		
			A4 devices		200		
E_G	Gain error	V_{OUT} = 0.5 V to V_S – 0.5 V, T_A = –40°C to +125°C	A1, A2, A3 devices		±0.05%	±0.2%	
			A4 device		±0.07%	±0.25%	
	Gain error drift	T_A = –40°C to +125°C			1.5	8	ppm/°C
	Nonlinearity error	V_{OUT} = 0.5 V to V_S – 0.5 V			±0.01%		
	Maximum capacitive load	No sustained oscillation			1		nF
VOLTAGE OUTPUT (2)							
V_{SP}	Swing to VS	R_L = 10 kΩ to GND, T_A = –40°C to +125°C			(V+) – 0.02	(V+) – 0.026	V
V_{SN}	Swing to GND	R_L = 10 kΩ to GND, V_{IN+} – $V_{IN–}$ = –10mV, T_A = –40°C to +125°C			(V_{GND}) + 0.0005	(V_{GND}) + 0.0035	V
V_{SG}	Zero current swing to GND	R_L = Open, V_{IN+} – $V_{IN–}$ = 0mV, V_{REF} = 0 V, T_A = –40°C to +125°C	A1 devices		(V_{GND}) + 0.0005	(V_{GND}) + 0.006	V
			A2, A3, A4 devices		(V_{GND}) + 0.0005	(V_{GND}) + 0.012	
FREQUENCY RESPONSE							
BW	Bandwidth	C_{LOAD} = 10 pF	A1 devices		350		kHz
			A2 devices		210		
			A3 devices		150		
			A4 devices		105		
SR	Slew rate				2		V/µs
NOISE, RTI (1)							
	Voltage noise density				40		nV/√Hz
POWER SUPPLY							
I_Q	Quiescent current	V_{SENSE} = 0 mV			200	260	µA
		V_{SENSE} = 0 mV, T_A = –40°C to +125°C				300	

(1) RTI = referred-to-input.
(2) See Typical Characteristic curve, Output Voltage Swing vs Output Current

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5.6 Typical Characteristics

at T_A = 25°C, V_S = 5 V, V_{REF} = V_S / 2, and V_{IN+} = 12 V (unless otherwise noted)

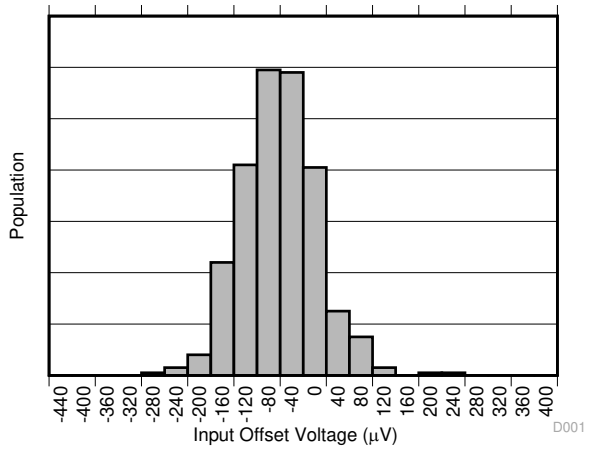


Figure 5-1. Input Offset Voltage Production Distribution A1

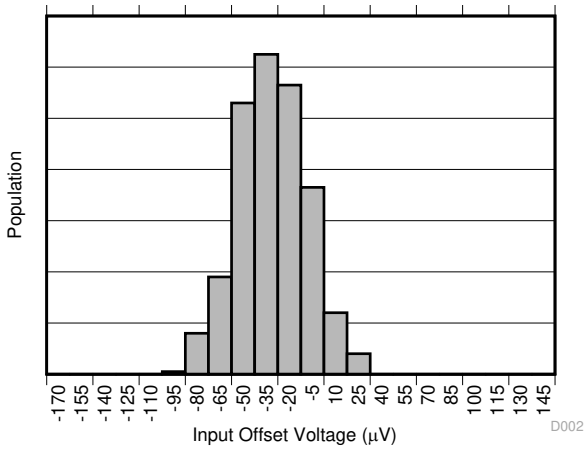


Figure 5-2. Input Offset Voltage Production Distribution A2

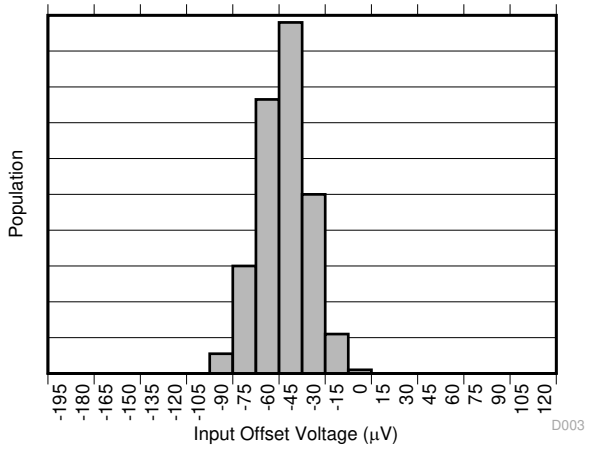


Figure 5-3. Input Offset Voltage Production Distribution A3

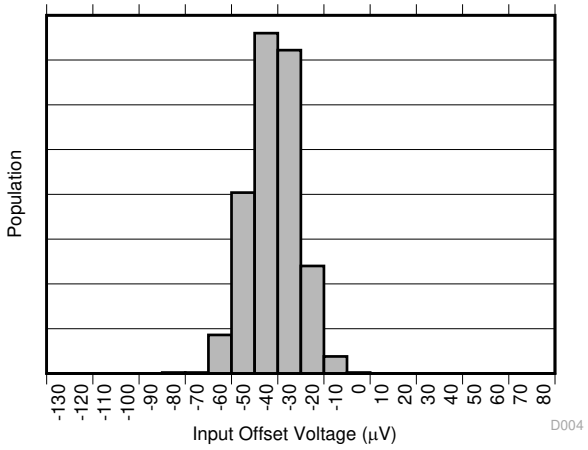


Figure 5-4. Input Offset Voltage Production Distribution A4

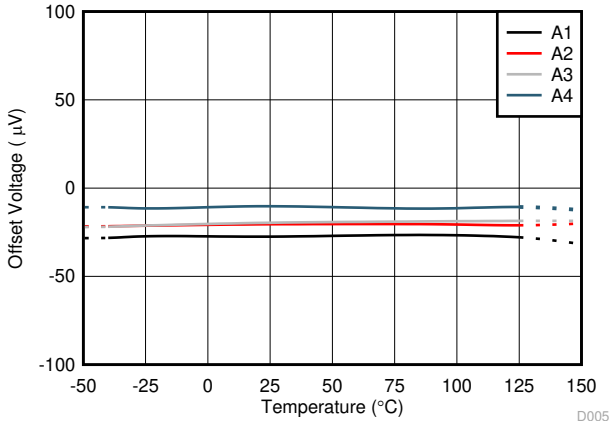


Figure 5-5. Offset Voltage vs Temperature

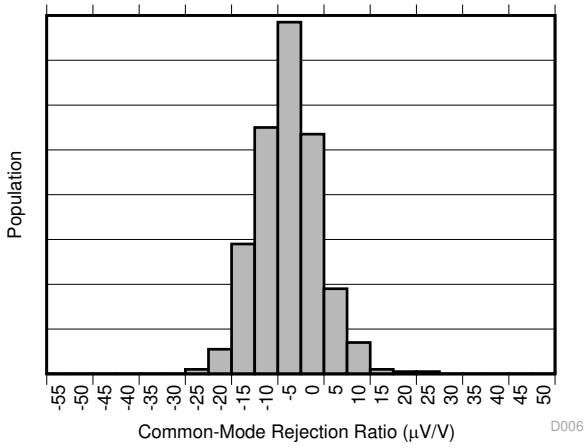


Figure 5-6. Common-Mode Rejection Production Distribution A1

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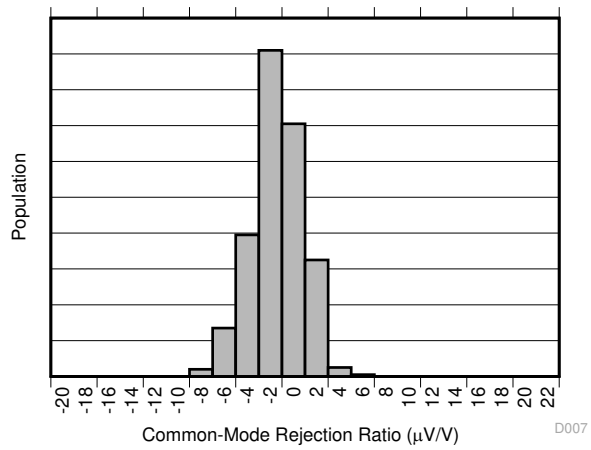


Figure 5-7. Common-Mode Rejection Production Distribution A2

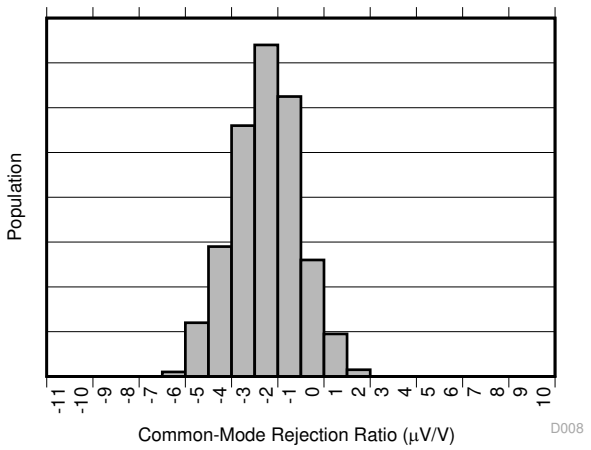


Figure 5-8. Common-Mode Rejection Production Distribution A3

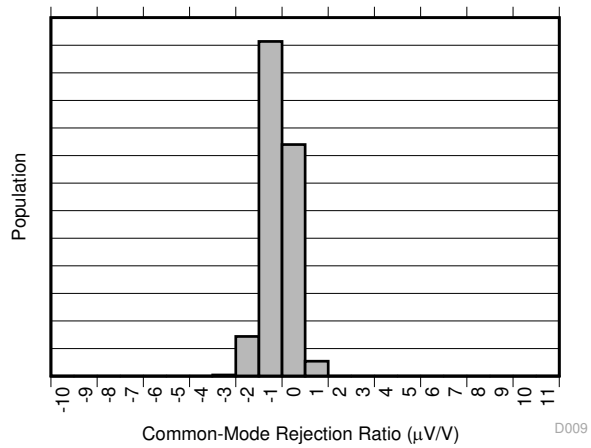


Figure 5-9. Common-Mode Rejection Production Distribution A4

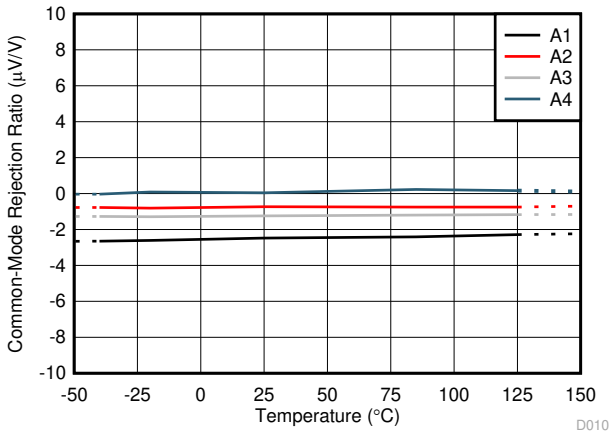


Figure 5-10. Common-Mode Rejection Ratio vs Temperature

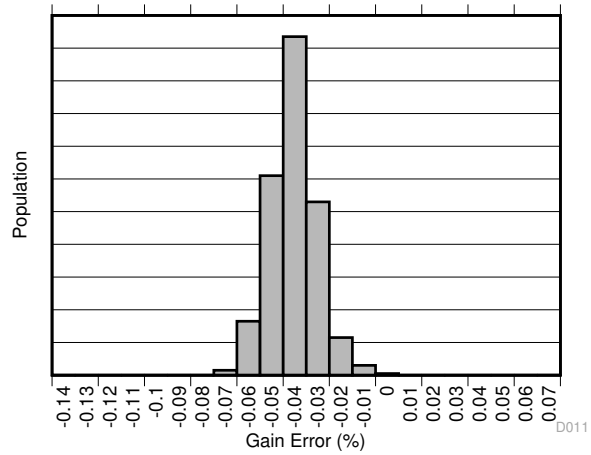


Figure 5-11. Gain Error Production Distribution A1

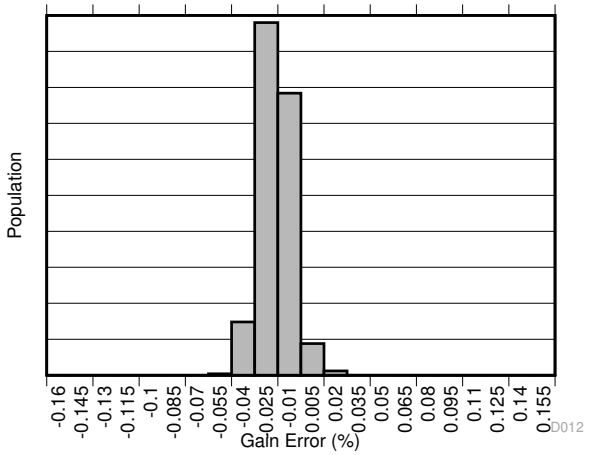


Figure 5-12. Gain Error Production Distribution A2

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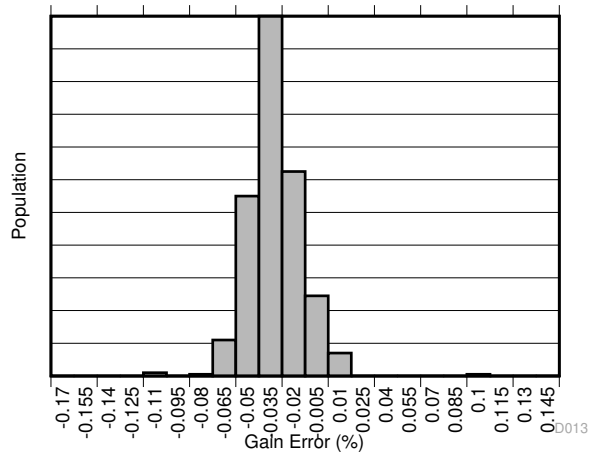


Figure 5-13. Gain Error Production Distribution A3

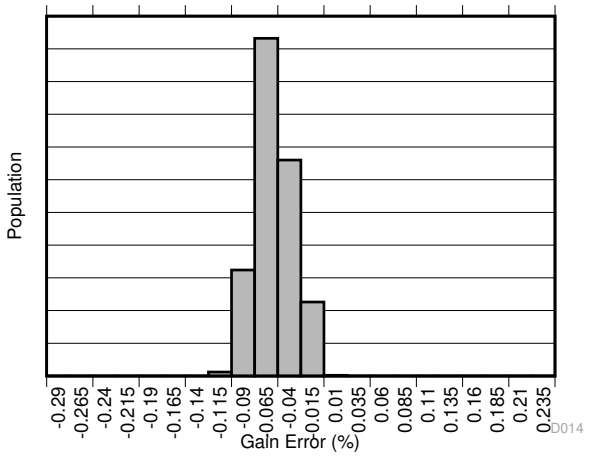


Figure 5-14. Gain Error Production Distribution A4

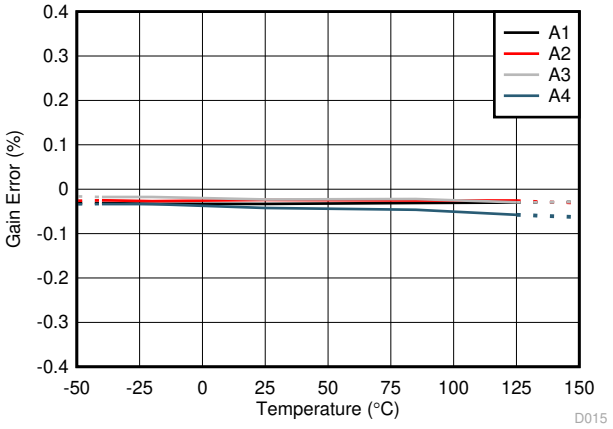


Figure 5-15. Gain Error vs Temperature

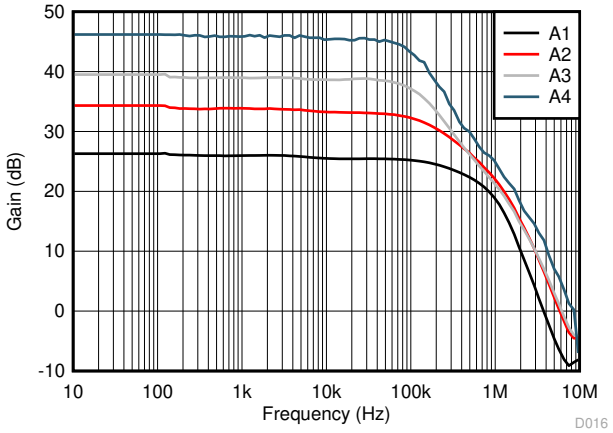


Figure 5-16. Gain vs Frequency

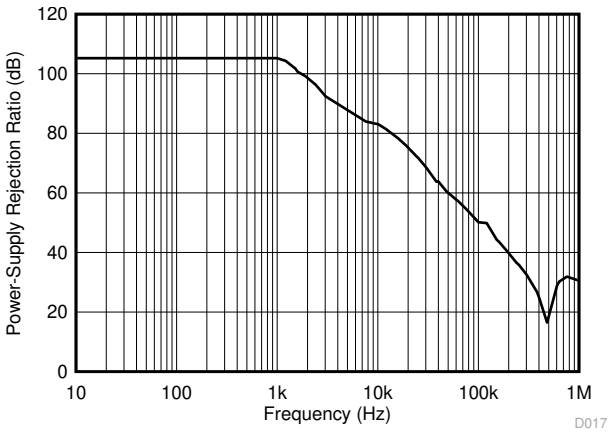


Figure 5-17. Power-Supply Rejection Ratio vs Frequency

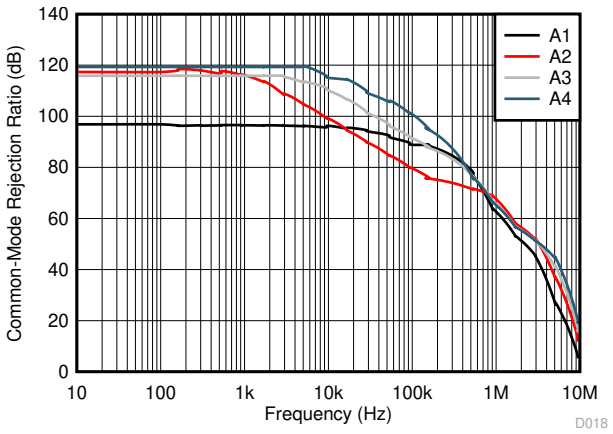


Figure 5-18. Common-Mode Rejection Ratio vs Frequency

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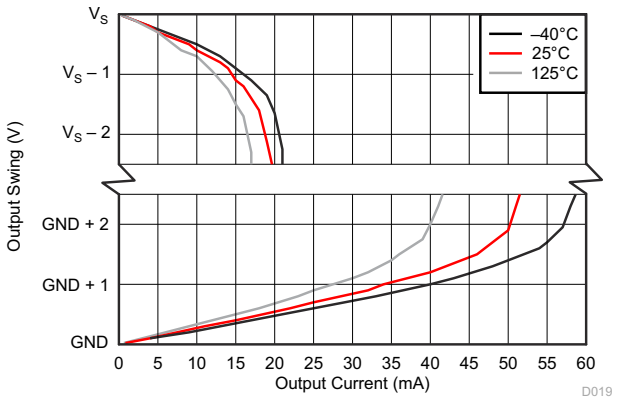
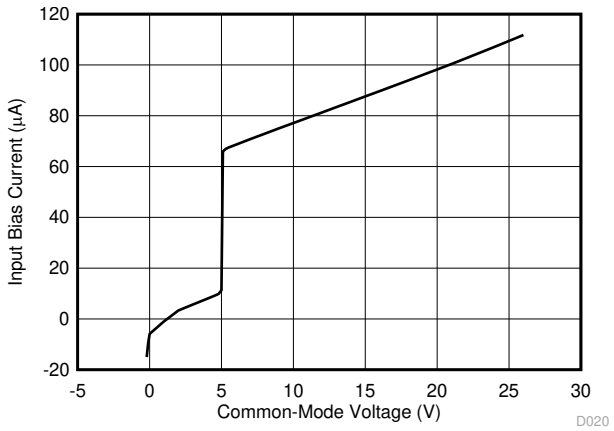
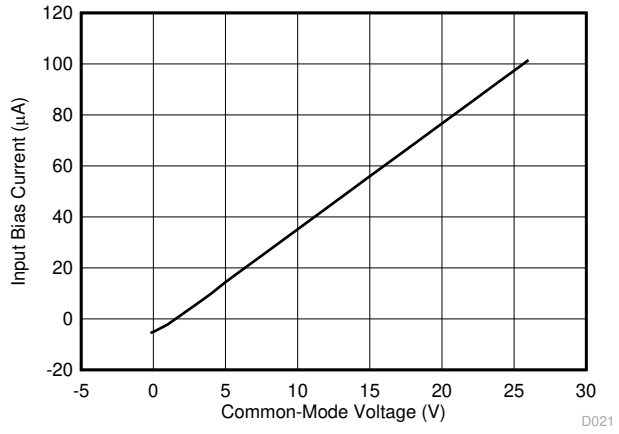


Figure 5-19. Output Voltage Swing vs Output Current



Supply voltage = 5 V

Figure 5-20. Input Bias Current vs Common-Mode Voltage



Supply voltage = 0 V

Figure 5-21. Input Bias Current vs Common-Mode Voltage (Both Inputs, Shutdown)

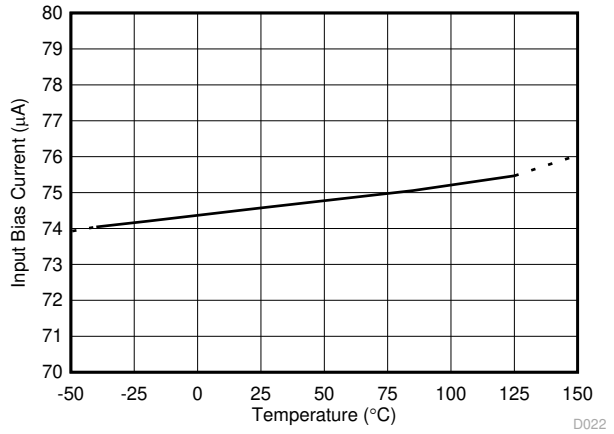


Figure 5-22. Input Bias Current vs Temperature

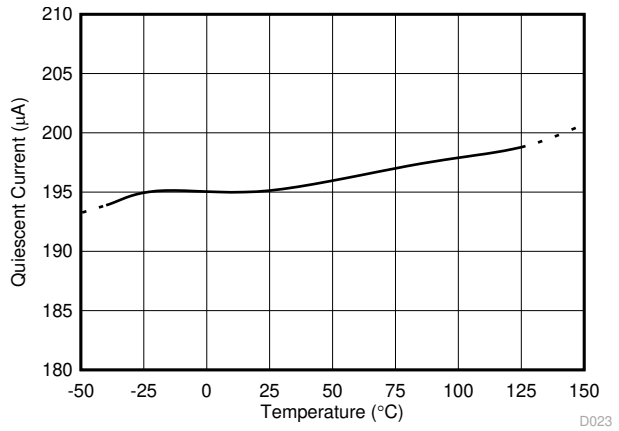


Figure 5-23. Quiescent Current vs Temperature

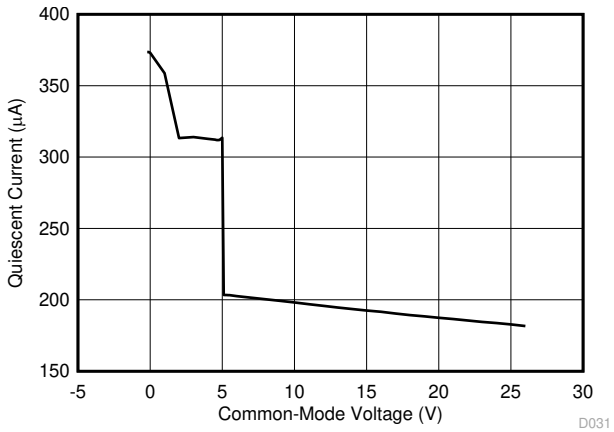


Figure 5-24. I_Q vs Common-Mode Voltage

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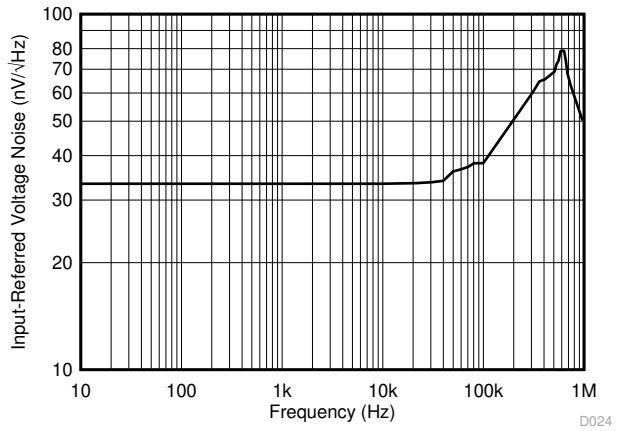


Figure 5-25. Input-Referred Voltage Noise vs Frequency (A3 Devices)

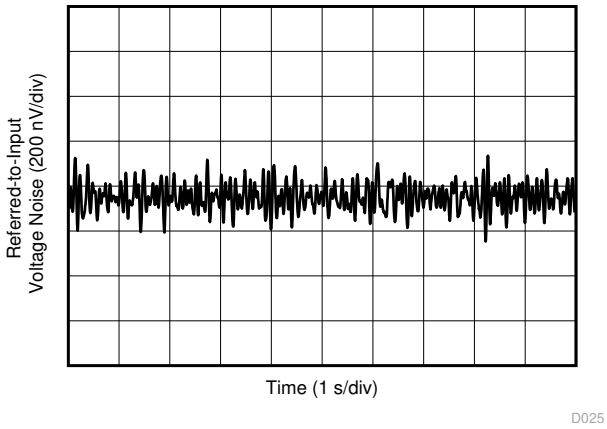
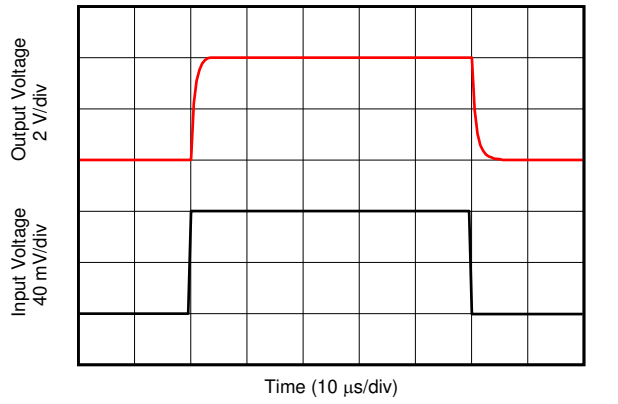


Figure 5-26. 0.1-Hz to 10-Hz Voltage Noise (Referred-to-Input)



80-mV_{PP} input step

Figure 5-27. Step Response

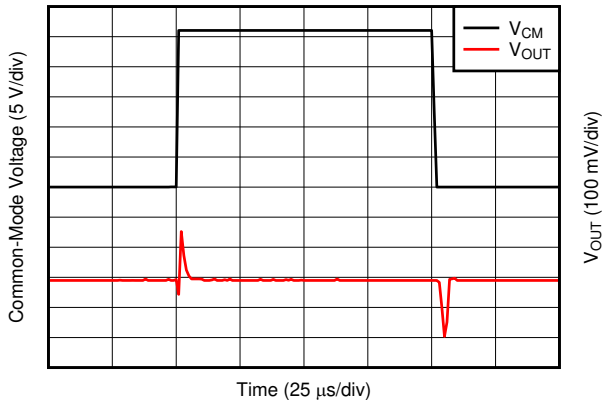


Figure 5-28. Common-Mode Voltage Transient Response

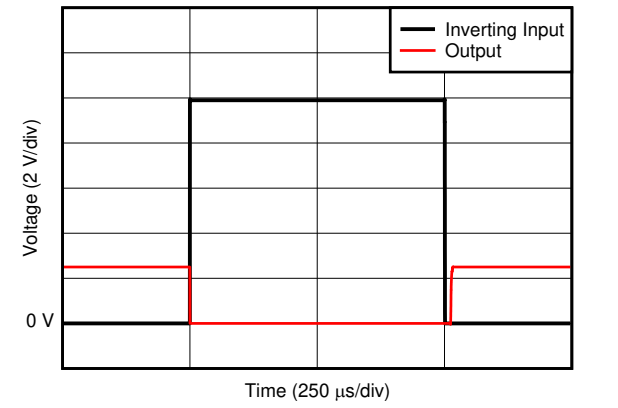


Figure 5-29. Inverting Differential Input Overload

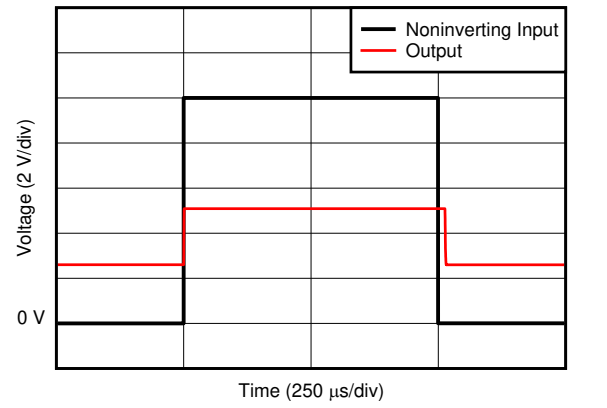


Figure 5-30. Noninverting Differential Input Overload

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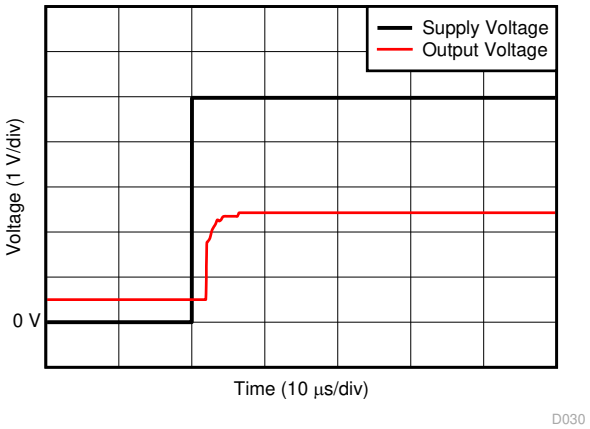


Figure 5-31. Start-Up Response

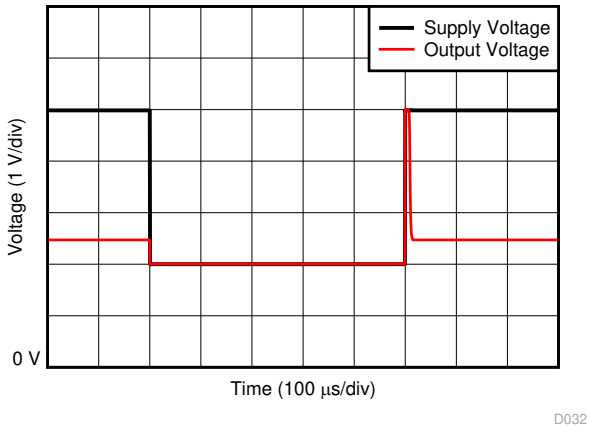


Figure 5-32. Brownout Recovery

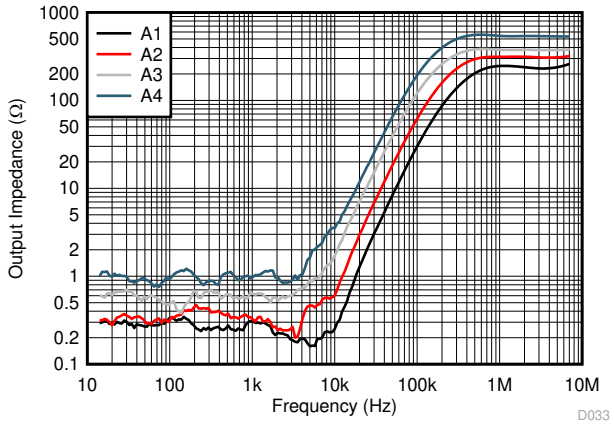


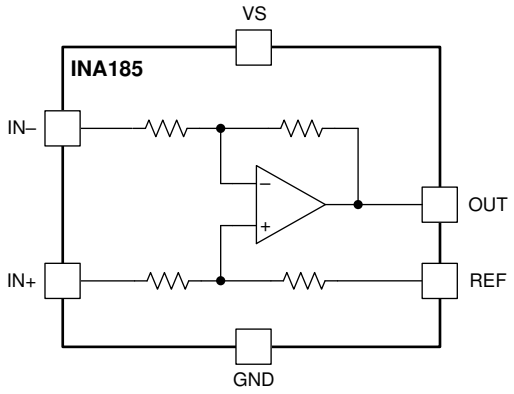
Figure 5-33. Output Impedance vs Frequency

6 Detailed Description

6.1 Overview

The INA185 is a 26-V common-mode current-sensing amplifier used in both low-side and high-side configurations. This specially-designed, current-sensing amplifier accurately measures voltages developed across current-sensing resistors on common-mode voltages that far exceed the supply voltage powering the device. Current can be measured on input voltage rails as high as 26 V, and the device can be powered from supply voltages as low as 2.7 V.

6.2 Functional Block Diagrams



6.3 Feature Description

6.3.1 High Bandwidth and Slew Rate

The INA185 supports small-signal bandwidths as high as 350 kHz, and large-signal slew rates of 2 V/µs. The ability to detect rapid changes in the sensed current, as well as the ability to quickly slew the output, make the INA185 a good choice for applications that require a quick response to input current changes. One application that requires high bandwidth and slew rate is low-side motor control, where the ability to follow rapid changing current in the motor allows for more accurate control over a wider operating range. Another application that requires higher bandwidth and slew rates is system fault detection, where the INA185 is used with an external comparator and a reference to quickly detect when the sensed current is out of range.

6.3.2 Bidirectional Current Monitoring

The INA185 senses current flow through a sense resistor in both directions. The bidirectional current-sensing capability is achieved by applying a voltage at the REF pin to offset the output voltage. A positive differential voltage sensed at the inputs results in an output voltage that is greater than the applied reference voltage. Likewise, a negative differential voltage at the inputs results in output voltage that is less than the applied reference voltage. Use Equation 1 to calculate the output voltage of the current-sense amplifier.

$$V_{OUT} = \left(I_{LOAD} \times R_{SENSE} \times GAIN\right) + V_{REF} \quad (1)$$

where

- I_{LOAD} is the load current to be monitored.
- R_{SENSE} is the current-sense resistor.
- GAIN is the gain option of the selected device.
- V_{REF} is the voltage applied to the REF pin.

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6.3.3 Wide Input Common-Mode Voltage Range

The INA185 supports input common-mode voltages from –0.2 V to +26 V. Due to the internal topology, the common-mode range is not restricted by the power-supply voltage (V_S) as long as V_S stays within the operational range of 2.7 V to 5.5 V. The ability to operate with common-mode voltages greater or less than V_S allows the INA185 to be used in high-side, as well as low-side, current-sensing applications, as shown in Figure 6-1.

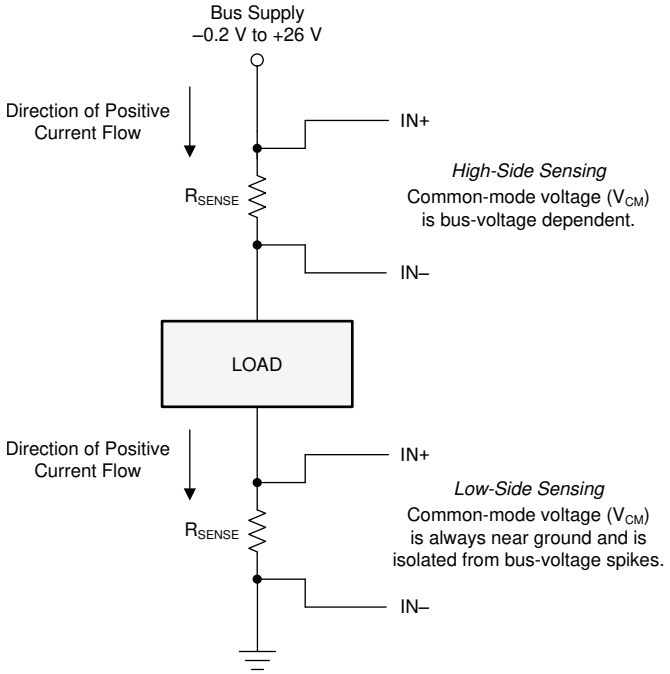


Figure 6-1. High-Side and Low-Side Sensing Connections

6.3.4 Precise Low-Side Current Sensing

When used in low-side current sensing applications, the offset voltage of the INA185 is within ±55 µV for A2, A3 and A4 devices. The low offset performance of the INA185 has two main benefits. First, the low offset allows these devices to be used in applications that must measure current over a wide dynamic range. In this case, the low offset improves the accuracy when the sensed currents are on the low end of the measurement range. The other advantage of low offset is the ability to sense lower voltage drop across the sense resistor accurately, thus allowing a lower-value shunt resistor. Lower-value shunt resistors reduce power loss in the current sense circuit, and help improve the power efficiency of the end application.

The gain error of the INA185 is specified to be within 0.2% of the actual value for A1, A2, and A3 devices. As the sensed voltage becomes much larger than the offset voltage, this voltage becomes the dominant source of error in the current sense measurement.

6.3.5 Rail-to-Rail Output Swing

The INA185 allows linear current sensing operation with the output close to the supply rail and GND. The maximum specified output swing to the positive rail is 25 mV, and the maximum specified output swing to GND is only 3.5 mV. To compare the output swing of the INA185 to an equivalent operational amplifier (op amp), the inputs are overdriven to approximate the open-loop condition specified in many operational amplifier data sheets. The current-sense amplifier is a closed-loop system, therefore the output swing to GND can be limited by the offset voltage and amplifier gain during unidirectional operation (V_{REF} = 0 V) when there is zero current flowing through the sense resistor. To define the maximum output voltage under the zero current condition, the INA185 *Electrical Characteristics* table specifies a maximum output voltage of 6 mV for the A1 device, and 12 mV for all other devices.

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6.4 Device Functional Modes

6.4.1 Normal Mode

The INA185 is in normal operation when the following conditions are met:

- The power supply voltage (V_S) is between 2.7 V and 5.5 V.
- The common-mode voltage (V_{CM}) is within the specified range of –0.2 V to +26 V.
- The maximum differential input signal multiplied by the gain plus V_{REF} is less than V_S minus the output voltage swing to V_S.
- The minimum differential input signal multiplied by the gain plus V_{REF} is greater than the swing to GND (see the *Rail-to-Rail Output Swing* section).

During normal operation, these devices produce an output voltage that is the *gained-up* representation of the difference voltage from IN+ to IN– plus the reference voltage at V_{REF}.

6.4.2 Unidirectional Mode

This device is capable of monitoring current flowing in one direction (unidirectional) or in both directions (bidirectional) depending on how the REF pin is configured. The most common case is unidirectional, where the output is set to ground when no current is flowing by connecting the REF pin to ground, as shown in Figure 6-2. When the current flows from the bus supply to the load, the input signal across IN+ to IN– increases, and causes the output voltage at the OUT pin to increase.

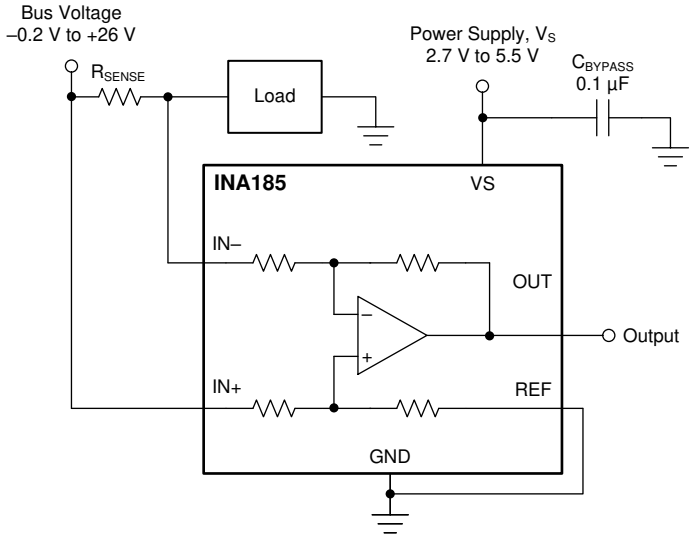


Figure 6-2. Unidirectional Application

The linear range of the output stage is limited by how close the output voltage can approach ground under zero input conditions. In unidirectional applications where measuring very low input currents is desirable, bias the REF pin to a convenient value above 50 mV to get the output into the linear range of the device. To limit common-mode rejection errors, buffer the reference voltage connected to the REF pin.

A less-frequently used output biasing method is to connect the REF pin to the power-supply voltage, V_S. This method results in the output voltage saturating at 25 mV less than the supply voltage when no differential input signal is present. This method is similar to the output saturated low condition with no input signal when the REF pin is connected to ground. The output voltage in this configuration only responds to negative currents that develop negative differential input voltage relative to the device IN– pin. Under these conditions, when the differential input signal increases negatively, the output voltage moves downward from the saturated supply voltage. The voltage applied to the REF pin must not exceed V_S.

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6.4.3 Bidirectional Mode

The INA185 is a bidirectional current-sense amplifier capable of measuring currents through a resistive shunt in two directions. This bidirectional monitoring is common in applications that include charging and discharging operations where the current flowing through the resistor can change directions.

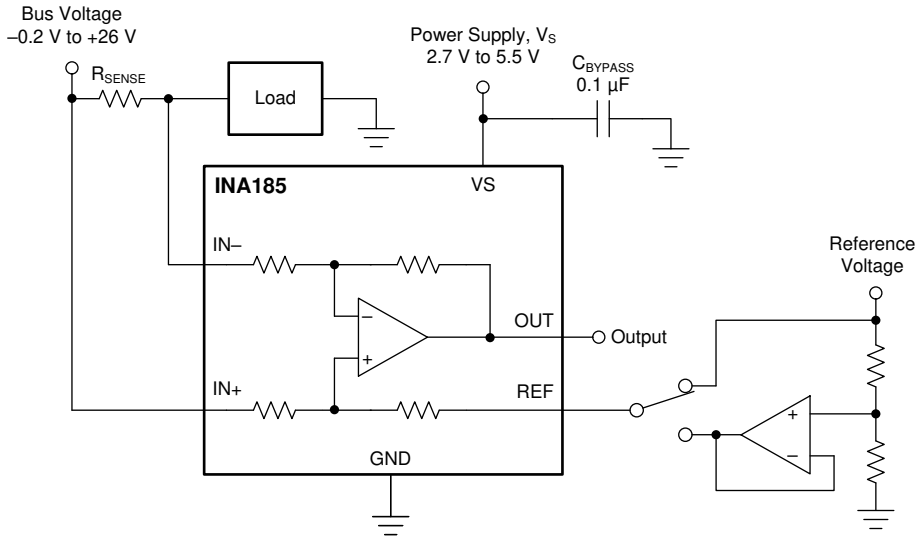


Figure 6-3. Bidirectional Application

The ability to measure this current flowing in both directions is enabled by applying a voltage to the REF pin, as shown in Figure 6-3. The voltage applied to REF (V_{REF}) sets the output state that corresponds to the zero-input level state. The output then responds by increasing above V_{REF} for positive differential signals (relative to the IN– pin) and responds by decreasing below V_{REF} for negative differential signals. This reference voltage applied to the REF pin can be set anywhere between 0 V to V_S. For bidirectional applications, V_{REF} is typically set at mid-scale for equal signal range in both current directions. In some cases, however, V_{REF} is set at a voltage other than midscale when the bidirectional current and corresponding output signal do not need to be symmetrical.

6.4.4 Input Differential Overload

If the differential input voltage ($V_{IN+} – V_{IN–}$) times gain plus the reference voltage exceeds the voltage swing specification, the INA185 drives the output as close as possible to the positive supply or ground, and does not provide accurate measurement of the differential input voltage. If this input overload occurs during normal circuit operation, then reduce the value of the shunt resistor or use a lower-gain version with the chosen sense resistor to avoid this mode of operation. If a differential overload occurs in a fault event, then the output of the INA185 returns to the expected value approximately 20 µs after the fault condition is removed.

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6.4.5 Shutdown Mode

Although the INA185 does not have a shutdown pin, the low power consumption of these devices allows the output of a logic gate or transistor switch to power the INA185. This gate or switch turns on and off the INA185 power-supply quiescent current.

However, in current shunt monitoring applications, the amount of current drained from the shunt circuit in shutdown conditions is also a concern. Evaluating this current drain involves considering the simplified schematic of the INA185 in shutdown mode, as shown in Figure 6-4.

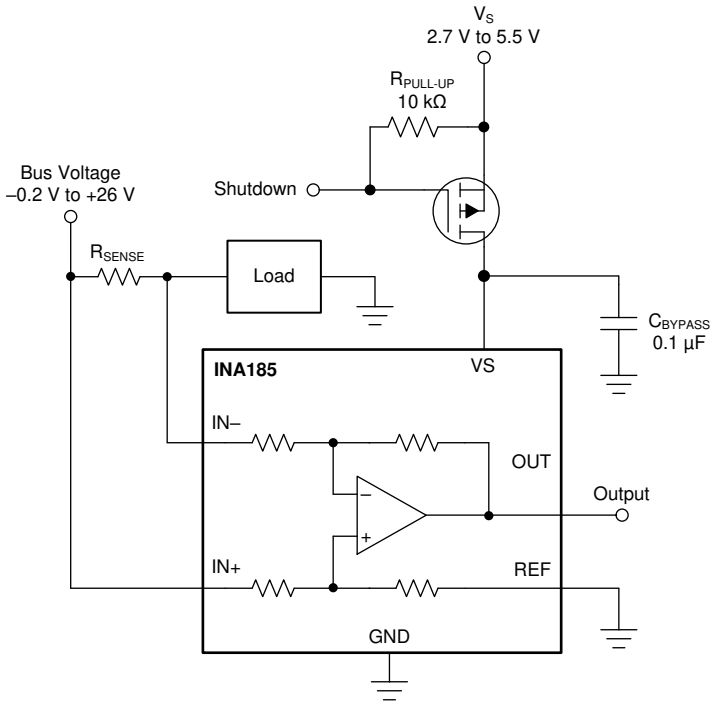


Figure 6-4. Basic Circuit to Shut Down the INA185 With a Grounded Reference

There is typically more than 500 kΩ of impedance (from the combination of 500-kΩ feedback and input gain set resistors) from each input of the INA185 to the OUT pin and to the REF pin. The amount of current flowing through these pins depends on the voltage at the connection. For example, if the REF pin is grounded, the calculation of the effect of the 500 kΩ impedance from the shunt to ground is straightforward. However, if the reference is powered while the INA185 is in shutdown mode, the input current will be determined by the 500-kΩ impedance and the voltage difference between the positive input and the voltage applied to the REF pin.

Regarding the 500-kΩ path to the output pin, the output stage of a disabled INA185 does constitute a good path to ground. Consequently, this current is directly proportional to a shunt common-mode voltage present across a 500-kΩ resistor.

As long as the shunt common-mode voltage is greater than V_S when the device is powered up, there is an additional and well-matched 55-µA typical current that flows in each of the inputs. If less than V_S, the common-mode input currents are negligible, and the only current effects are the result of the 500-kΩ resistors.

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7 Application and Implementation

Note

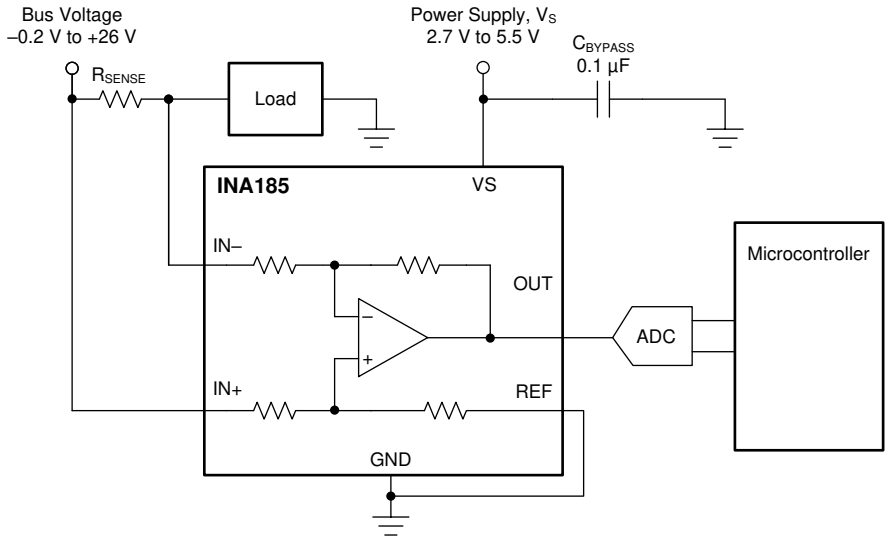
Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

7.1 Application Information

The INA185 amplifies the voltage developed across a current-sensing resistor as current flows through the resistor to the load or ground. The ability to drive the reference pin to adjust the functionality of the output signal offers multiple configurations, as discussed in previous sections.

7.1.1 Basic Connections

Figure 7-1 shows the basic connections of the INA185. Connect the input pins (IN+ and IN–) to the shunt resistor as close as possible to minimize any resistance in series with the shunt resistor.



NOTE: To help eliminate ground offset errors between the device and the analog-to-digital converter (ADC), connect the REF pin to the ADC reference input and then to ground. For best performance, use an RC filter between the output of the INA185 and the ADC. See the *Closed-Loop Analysis of Load-Induced Amplifier Stability Issues Using ZOUT* application note for more details.

Figure 7-1. Basic Connections for the INA185

A power-supply bypass capacitor of at least 0.1 µF is required for proper operation. Applications with noisy or high-impedance power supplies can require additional decoupling capacitors to reject power-supply noise. Connect bypass capacitors close to the device pins.

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7.1.2 R_{SENSE} and Device Gain Selection

User can choose a current-sense resistor that is as large as possible to maximize the accuracy of the INA185. A large sense resistor maximizes the differential input signal for a given amount of current flow and reduces the error contribution of the offset voltage. However, there are practical limits as to how large the current-sense resistor can be in a given application. The INA185 has a typical input bias current of 75 µA for each input when operated at a 12-V common-mode voltage input. When large current-sense resistors are used, these bias currents cause increased offset error and reduced common-mode rejection. Therefore, using current-sense resistors larger than a few ohms is generally not recommended for applications that require current-monitoring accuracy. Another common restriction on the value of the current-sense resistor is the maximum allowable power dissipation that is budgeted for the resistor. Equation 2 gives the maximum value for the current sense resistor for a given power dissipation budget:

$$R_{SENSE} < \frac{PD_{MAX}}{I_{MAX}^2} \tag{2}$$

where:

- PD_{MAX} is the maximum allowable power dissipation in R_{SENSE}.
- I_{MAX} is the maximum current that flows through R_{SENSE}.

An additional limitation on the size of the current-sense resistor and device gain is due to the power-supply voltage, V_S, and device swing-to-rail limitations. To make sure that the current-sense signal is properly passed to the output, both positive and negative output swing limitations must be examined. Equation 3 provides the maximum values of R_{SENSE} and GAIN to keep the device from hitting the positive swing limitation.

$$I_{MAX} \times R_{SENSE} \times GAIN < V_{SP} - V_{REF} \tag{3}$$

where:

- I_{MAX} is the maximum current that flows through R_{SENSE}.
- GAIN is the gain of the current sense-amplifier.
- V_{SP} is the positive output swing specified in the data sheet.
- V_{REF} is the externally applied voltage on the REF pin.

To avoid positive output swing limitations when selecting the value of R_{SENSE}, there is always a trade-off between the value of the sense resistor and the gain of the device to consider. If the sense resistor selected for the maximum power dissipation is too large, then selecting a lower-gain device to avoid positive swing limitations is possible.

The negative swing limitation places a limit on how small of a sense resistor can be used in a given application. Equation 4 provides the limit on the minimum size of the sense resistor.

$$I_{MIN} \times R_{SENSE} \times GAIN > V_{SN} - V_{REF} \tag{4}$$

where:

- I_{MIN} is the minimum current that flows through R_{SENSE}.
- GAIN is the gain of the current sense amplifier.
- V_{SN} is the negative output swing of the device (see *Rail-to-Rail Output Swing*).
- V_{REF} is the externally applied voltage on the REF pin.

In addition to adjusting the offset and gain, the voltage applied to the REF pin can be slightly increased to avoid negative swing limitations.

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7.1.3 Signal Filtering

Provided that the INA185 output is connected to a high-impedance input, the best location to filter is at the device output using a simple RC network from OUT to GND. Filtering at the output attenuates high-frequency disturbances in the common-mode voltage, differential input signal, and the INA185 power-supply voltage. If filtering at the output is not possible, or filtering of only the differential input signal is required, then apply a filter at the input pins of the device. Figure 7-2 provides an example of how a filter can be used on the input pins of the device.

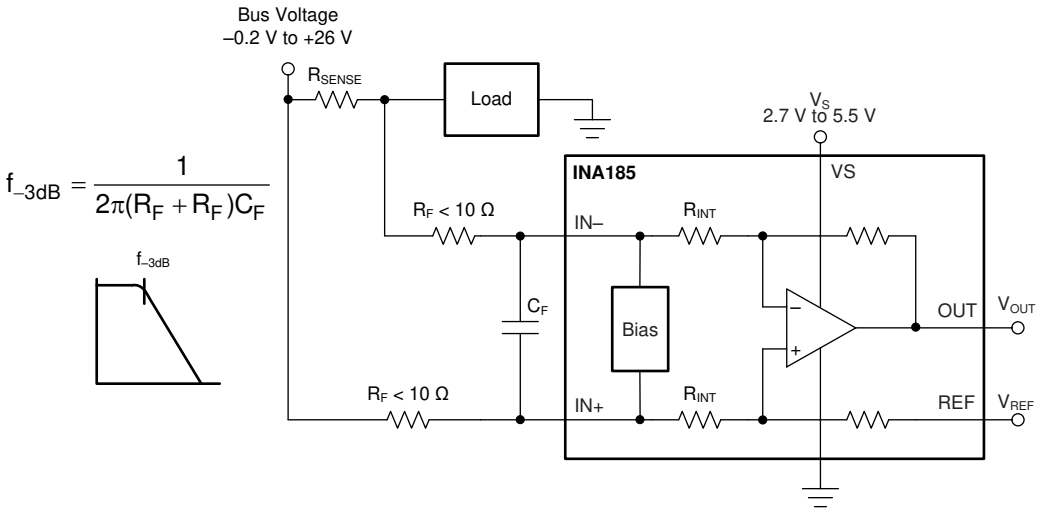


Figure 7-2. Filter at Input Pins

The addition of external series resistance creates an additional error in the measurement, therefore the value of these series resistors must be kept to 10 Ω (or less, if possible) to reduce impact to accuracy. The internal bias network (Figure 7-2) present at the input pins creates a mismatch in input bias currents when a differential voltage is applied between the input pins. If additional external series filter resistors are added to the circuit, the mismatch in bias currents results in a mismatch of voltage drops across the filter resistors. This mismatch creates a differential error voltage that subtracts from the voltage developed across the shunt resistor. This error results in a voltage at the device input pins that is different than the voltage developed across the shunt resistor. Without the additional series resistance, the mismatch in input bias currents has little effect on device operation. Use Equation 5 to calculate the gain error factor, then use Equation 6 to calculate the amount of error these external filter resistors add to the measurement.

The amount of variance in the differential voltage present at the device input relative to the voltage developed at the shunt resistor is based both on the external series resistance (R_F) value as well as the internal input resistor R_{INT}, as shown in Figure 7-2. The reduction of the shunt voltage reaching the device input pins appears as a gain error when comparing the output voltage relative to the voltage across the shunt resistor. A factor can be calculated to determine the amount of gain error that is introduced by the addition of external series resistance. Use Equation 5 to calculate the expected deviation from the shunt voltage to what is measured at the device input pins:

$$\text{Gain Error Factor} = \frac{1250 \times R_{INT}}{(1250 \times R_F) + (1250 \times R_{INT}) + (R_F \times R_{INT})} \quad (5)$$

where:

- R_{INT} is the internal input resistor.
- R_F is the external series resistance.

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With the adjustment factor from Equation 5, including the device internal input resistance, this factor varies with each gain version, as shown in Table 7-1. Each individual device gain error factor is shown in Table 7-2.

Table 7-1. Input Resistance

PRODUCT	GAIN	R_{INT} (kΩ)
INA185A1	20	25
INA185A2	50	10
INA185A3	100	5
INA185A4	200	2.5

Table 7-2. Device Gain Error Factor

PRODUCT	SIMPLIFIED GAIN ERROR FACTOR
INA185A1	$\frac{25000}{(21 \times R_F) + 25000}$
INA185A2	$\frac{10000}{(9 \times R_F) + 10000}$
INA185A3	$\frac{1000}{R_F + 1000}$
INA185A4	$\frac{2500}{(3 \times R_F) + 2500}$

The gain error that can be expected from the addition of the external series resistors can then be calculated based on Equation 6:

$$\text{Gain Error (\%)} = 100 - (100 \times \text{Gain Error Factor}) \quad (6)$$

For example, using an INA185A2 and the corresponding gain error equation from Table 7-2, a series resistance of 10 Ω results in a gain error factor of 0.991. The corresponding gain error is then calculated using Equation 6, resulting in an additional gain error of approximately 0.89% solely because of the external 10-Ω series resistors.

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7.2 Typical Application

One application for the INA185 is to monitor bidirectional currents. Bidirectional currents are present in systems that have to monitor currents in both directions; common examples are monitoring the charging and discharging of batteries and bidirectional current monitoring in motor control. Figure 7-3 shows the device configuration for bidirectional current monitoring. Applying stable REF pin voltage closer to the middle of device supply voltage allows both positive- and negative-current monitoring, as shown in this configuration. Configure the INA185 to monitor unidirectional currents by grounding the REF pin.

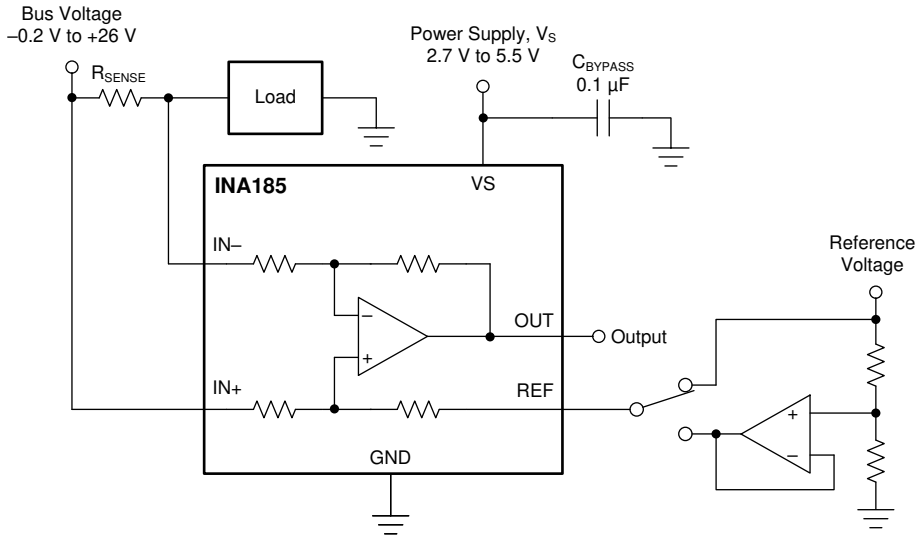


Figure 7-3. Measuring Bidirectional Current

7.2.1 Design Requirements

The design requirements for the circuit shown in Figure 7-3, are listed in Table 7-3.

Table 7-3. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE
Power-supply voltage, V_S	5 V
Bus supply rail, V_{CM}	12 V
R_{SENSE} power loss	< 450 mW
Maximum sense current, I_{MAX}	±20 A
Current sensing error	Less than 1% at maximum current, T_J = 25°C
Small-signal bandwidth	> 100 kHz

7.2.2 Detailed Design Procedure

The maximum value of the current sense resistor is calculated based on the maximum power loss requirement. By applying Equation 2, the maximum value of the current-sense resistor is 1.125 mΩ. This is the maximum value for sense resistor R_{SENSE}; therefore, set R_{SENSE} to 1 mΩ as this value is the closest standard resistor value that meets the power-loss requirement.

The next step is to select the appropriate gain and reduce R_{SENSE}, if needed, to keep the output signal swing within the V_S range. The design requirements call for bidirectional current monitoring; therefore, a voltage between 0 and V_S must be applied to the REF pin. The bidirectional currents monitored are symmetric around 0 (that is, ±20 A); therefore, the ideal voltage to apply to V_{REF} is V_S / 2 or 2.5 V. If the positive current is greater than the negative current, using a lower voltage on V_{REF} has the benefit of maximizing the output swing for the given range of expected currents. Using Equation 3, and given that I_{MAX} = 20 A , R_{SENSE} = 1 mΩ, and V_{REF} = 2.5 V, the maximum current-sense gain calculated to avoid the positive swing-to-rail limitations on the output is 122.5 V/V. Likewise, using Equation 4 for the negative-swing limitation results in a maximum gain of 124.75 V/V.

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Selecting the gain-of-100 device maximizes the output range while staying within the output swing range. If the maximum calculated gains are slightly less than 100 V/V, the value of the current-sense resistor can be reduced to keep the output from hitting the output-swing limitations.

To calculate the accuracy at peak current, the two factors that must be determined are the gain error and the offset error. The gain error of the INA185A3 is specified to be a maximum of 0.2%. The error due to the offset is constant, and is specified to be 130 µV (maximum) for the conditions where V_{CM} = 12 V and V_S = 5 V. Using Equation 7, the percentage error contribution of the offset voltage is calculated to be 0.65%, with total offset error = 130 µV, R_{SENSE} = 1 mΩ, and I_{SENSE} = 20 A.

$$\text{Total Offset Error (\%)} = \frac{\text{Total Offset Error (V)}}{I_{SENSE} \times R_{SENSE}} \times 100\% \tag{7}$$

One method of calculating the total error is to add the gain error to the percentage contribution of the offset error. However, in this case, the gain error and the offset error do not have an influence or correlation to each other. A more statistically-accurate method of calculating the total error is to use the RSS sum of the errors, as shown in Equation 8:

$$\text{Total Error (\%)} = \sqrt{\text{Total Gain Error (\%)}^2 + \text{Total Offset Error (\%)}^2} \tag{8}$$

After applying Equation 8, the total current sense error at maximum current is calculated to be 0.68%, which is less than the design example requirement of 1%.

The INA185A3 (gain = 100 V/V) also has a bandwidth of 150 kHz that meets the small-signal bandwidth requirement of 100 kHz. If higher bandwidth is required, lower-gain devices can be used at the expense of either reduced output voltage range or an increased value of R_{SENSE}.

7.2.3 Application Curve

Figure 7-4 shows an example output response of a bidirectional configuration. With the REF pin connected to a reference voltage (2.5 V in this case), the output voltage is biased upwards by this reference level. The output rises above the reference voltage for positive differential input signals, and falls below the reference voltage for negative differential input signals.

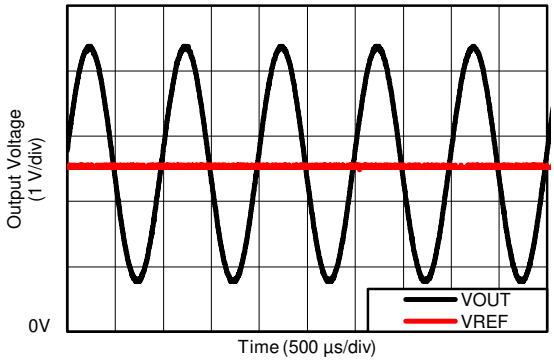


Figure 7-4. Bidirectional Application Output Response

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7.3 Power Supply Recommendations

The input circuitry of the INA185 allows for accurate measurements beyond the power-supply voltage, V_S. For example, V_S can be 5 V, whereas the bus supply voltage at IN+ and IN– can be as high as 26 V. However, the output voltage range of the OUT pin is limited by the voltages on the VS pin. The INA185 also withstands the full differential input signal range up to 26 V at the IN+ and IN– input pins, regardless of whether or not the device has power applied at the VS pin.

7.3.1 Common-Mode Transients Greater Than 26 V

With a small amount of additional circuitry, the INA185 can be used in circuits that are subjected to transients higher than 26 V, such as automotive applications. Use only Zener diodes or Zener-type transient absorbers (sometimes referred to as *transorbs*)—any other type of transient absorber has an unacceptable time delay. Start by adding a pair of resistors as a working impedance for the Zener diode. See Figure 7-5. Keep these resistors as small as possible; most often, around 10 Ω. Larger values can be used with an effect on gain that is discussed in the *Signal Filtering* section. This circuit limits only short-term transients, therefore many applications are satisfied with a 10-Ω resistor along with conventional Zener diodes of the lowest acceptable power rating. This combination uses the least amount of board space. These diodes can be found in packages as small as SOT-523 or SOD-523.

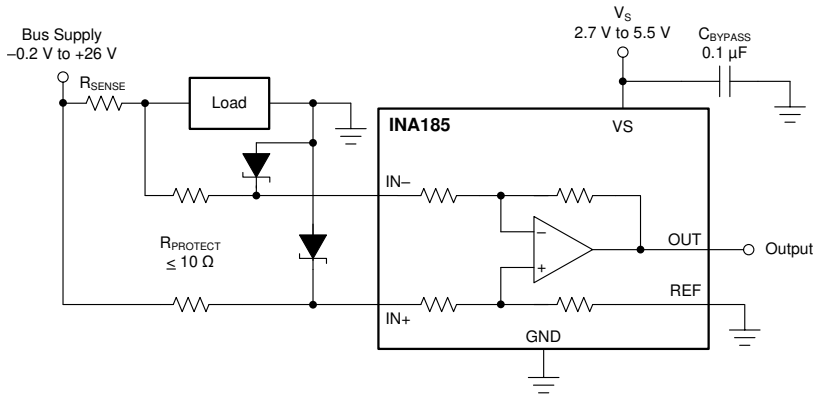


Figure 7-5. Transient Protection Using Dual Zener Diodes

In the event that low-power Zener diodes do not have sufficient transient absorption capability, a higher-power transorb must be used. The most package-efficient solution involves using a single transorb and back-to-back diodes between the device inputs, as shown in Figure 7-6. The most space-efficient solutions are dual, series-connected diodes in a single SOT-523 or SOD-523 package. In either of the examples shown in Figure 7-5 and Figure 7-6, the total board area required by the INA185 with all protective components is less than that of an SO-8 package, and only slightly greater than that of an MSOP-8 package.

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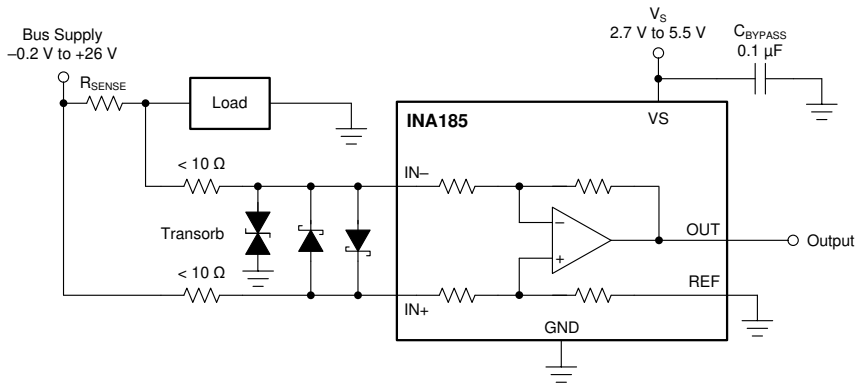


Figure 7-6. Transient Protection Using a Single Transorb and Input Clamps

For more information, see the *Current Shunt Monitor With Transient Robustness* reference design.

7.4 Layout

7.4.1 Layout Guidelines

- Connect the input pins to the sensing resistor using a Kelvin or 4-wire connection. This connection technique makes sure that only the current-sensing resistor impedance is detected between the input pins. Poor routing of the current-sensing resistor commonly results in additional resistance present between the input pins. Given the very-low ohmic value of the current resistor, any additional high-current carrying impedance can cause significant measurement errors.
- Place the power-supply bypass capacitor as close as possible to the device power supply and ground pins. The recommended value of this bypass capacitor is 0.1 µF. Additional decoupling capacitance can be added to compensate for noisy or high-impedance power supplies.
- When routing the connections from the current sense resistor to the device, keep the trace lengths as close as possible to minimize any impedance mismatch.

7.4.2 Layout Example

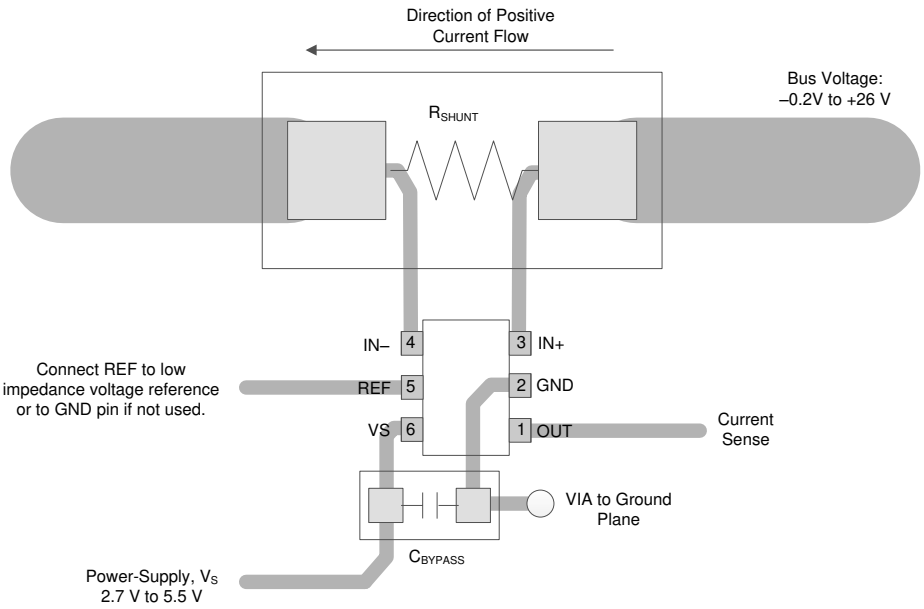


Figure 7-7. SOT-563 Recommended Layout

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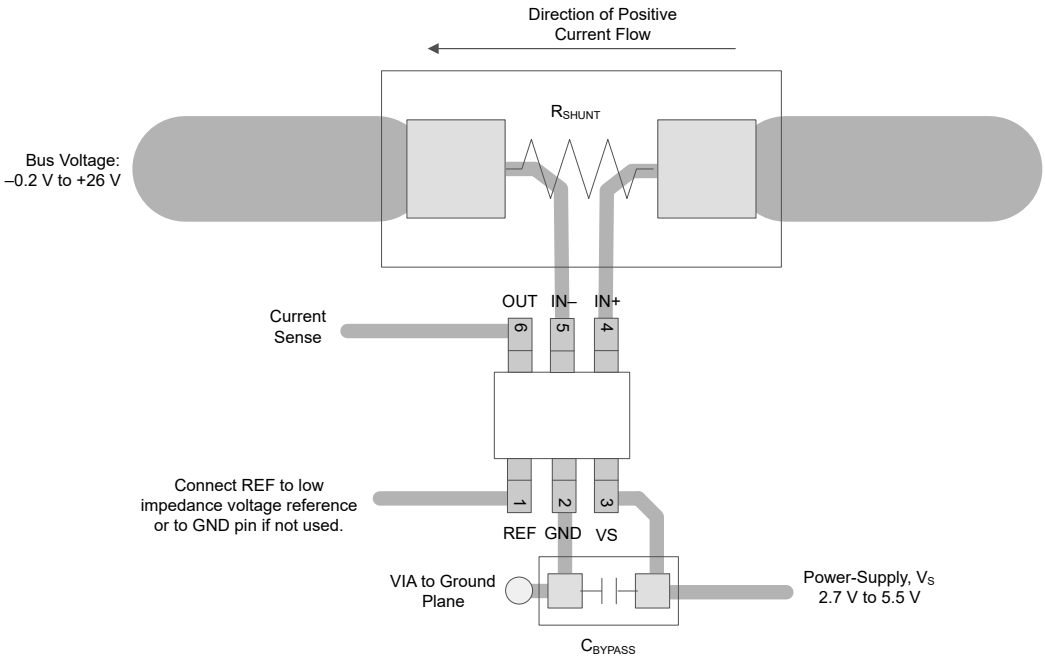


Figure 7-8. SC70 Recommended Layout

8 Device and Documentation Support

8.1 Device Support

8.1.1 Development Support

Texas Instruments, *Current shunt monitor with transient robustness* reference design

8.2 Documentation Support

8.2.1 Related Documentation

For related documentation see the following:

- Texas Instruments, *INA185EVM* user's guide

8.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

8.4 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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8.5 Trademarks

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8.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

8.7 Glossary

TI Glossary	This glossary lists and explains terms, acronyms, and definitions.

9 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision * (March 2019) to Revision A (November 2023)	Page
• Changed the numbering format for tables, figures, and cross-references throughout the document	1
• Changed *Device Information* table to *Package Information*	1
• Added DCK (SC70, 6) package to the data sheet	1

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
INA185A1IDCKR	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1PS
INA185A1IDCKR.B	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1PS
INA185A1IDRLR	Active	Production	SOT-5X3 (DRL) | 6	4000 | LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	1DV
INA185A1IDRLR.B	Active	Production	SOT-5X3 (DRL) | 6	4000 | LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	1DV
INA185A1IDRLT	Active	Production	SOT-5X3 (DRL) | 6	250 | SMALL T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	1DV
INA185A1IDRLT.B	Active	Production	SOT-5X3 (DRL) | 6	250 | SMALL T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	1DV
INA185A2IDCKR	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1PT
INA185A2IDCKR.B	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1PT
INA185A2IDRLR	Active	Production	SOT-5X3 (DRL) | 6	4000 | LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	1DW
INA185A2IDRLR.B	Active	Production	SOT-5X3 (DRL) | 6	4000 | LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	1DW
INA185A2IDRLT	Obsolete	Production	SOT-5X3 (DRL) | 6	-	-	Call TI	Call TI	-40 to 125	1DW
INA185A3IDCKR	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1PU
INA185A3IDCKR.B	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1PU
INA185A3IDRLR	Active	Production	SOT-5X3 (DRL) | 6	4000 | LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	1DX
INA185A3IDRLR.B	Active	Production	SOT-5X3 (DRL) | 6	4000 | LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	1DX
INA185A3IDRLT	Obsolete	Production	SOT-5X3 (DRL) | 6	-	-	Call TI	Call TI	-40 to 125	1DX
INA185A4IDCKR	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1PV
INA185A4IDCKR.B	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1PV
INA185A4IDRLR	Active	Production	SOT-5X3 (DRL) | 6	4000 | LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	1DZ
INA185A4IDRLR.B	Active	Production	SOT-5X3 (DRL) | 6	4000 | LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	1DZ
INA185A4IDRLT	Obsolete	Production	SOT-5X3 (DRL) | 6	-	-	Call TI	Call TI	-40 to 125	1DZ

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF INA185 :

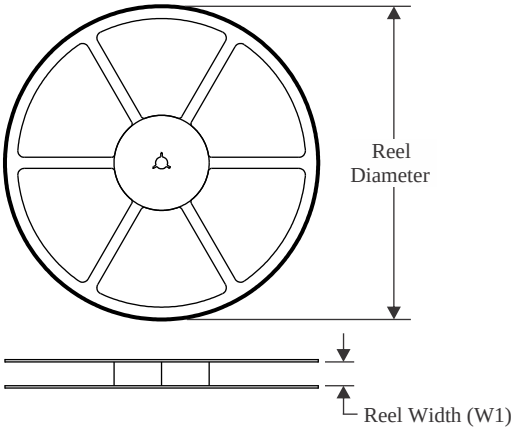
- Automotive : INA185-Q1

NOTE: Qualified Version Definitions:

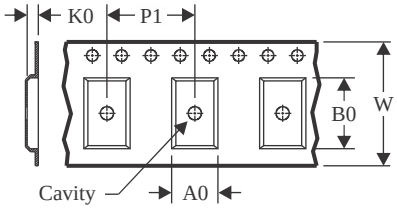
- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

TAPE AND REEL INFORMATION

REEL DIMENSIONS

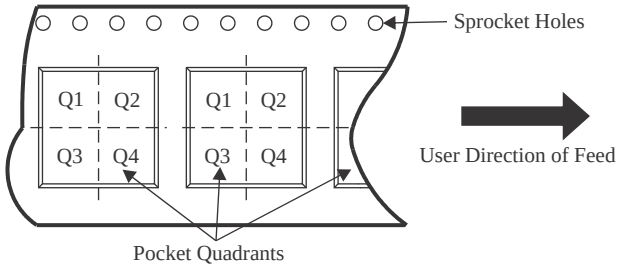


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

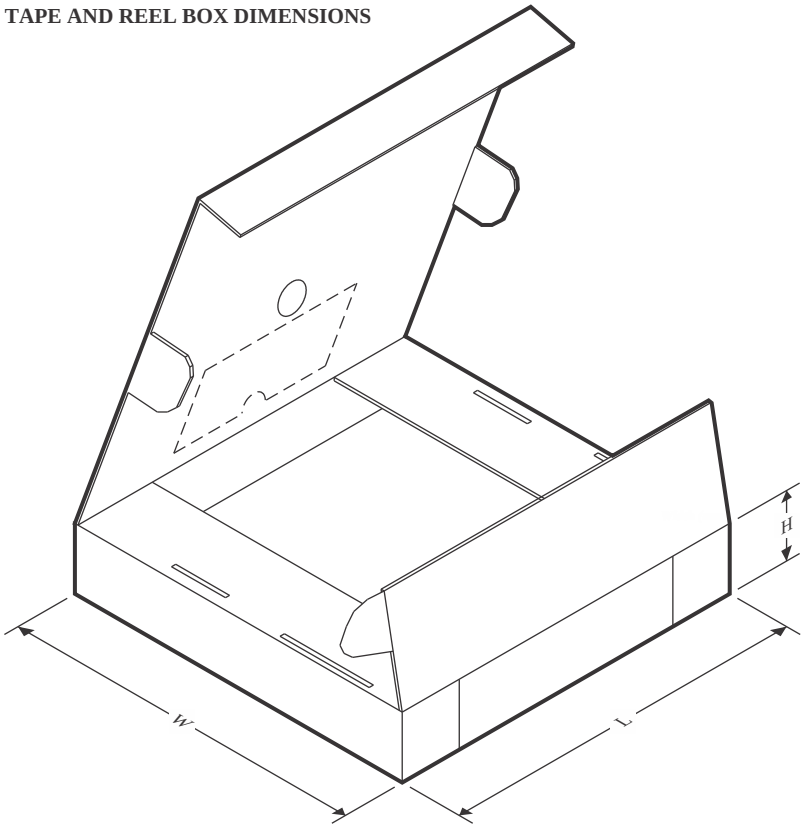
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
INA185A1IDCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA185A1IDRLR	SOT-5X3	DRL	6	4000	180.0	8.4	1.98	1.78	0.69	4.0	8.0	Q3
INA185A1IDRLT	SOT-5X3	DRL	6	250	180.0	8.4	1.98	1.78	0.69	4.0	8.0	Q3
INA185A2IDCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA185A2IDRLR	SOT-5X3	DRL	6	4000	180.0	8.4	1.98	1.78	0.69	4.0	8.0	Q3
INA185A3IDCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA185A3IDRLR	SOT-5X3	DRL	6	4000	180.0	8.4	1.98	1.78	0.69	4.0	8.0	Q3
INA185A4IDCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA185A4IDRLR	SOT-5X3	DRL	6	4000	180.0	8.4	1.98	1.78	0.69	4.0	8.0	Q3

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
INA185A1IDCKR	SC70	DCK	6	3000	180.0	180.0	18.0
INA185A1IDRLR	SOT-5X3	DRL	6	4000	183.0	183.0	20.0
INA185A1IDRLT	SOT-5X3	DRL	6	250	183.0	183.0	20.0
INA185A2IDCKR	SC70	DCK	6	3000	180.0	180.0	18.0
INA185A2IDRLR	SOT-5X3	DRL	6	4000	183.0	183.0	20.0
INA185A3IDCKR	SC70	DCK	6	3000	180.0	180.0	18.0
INA185A3IDRLR	SOT-5X3	DRL	6	4000	183.0	183.0	20.0
INA185A4IDCKR	SC70	DCK	6	3000	180.0	180.0	18.0
INA185A4IDRLR	SOT-5X3	DRL	6	4000	183.0	183.0	20.0

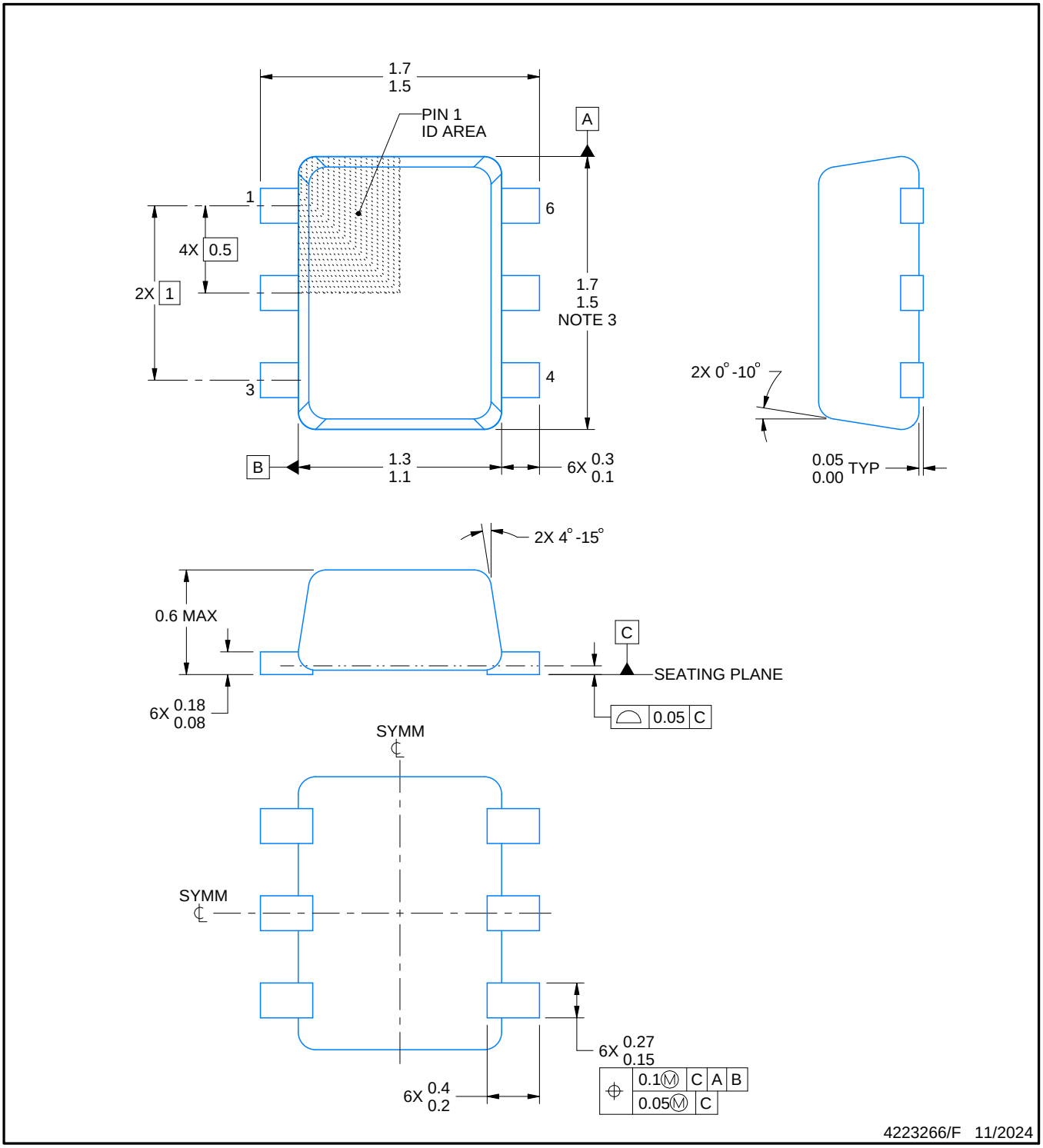


PACKAGE OUTLINE

DRL0006A

SOT - 0.6 mm max height

PLASTIC SMALL OUTLINE



NOTES:

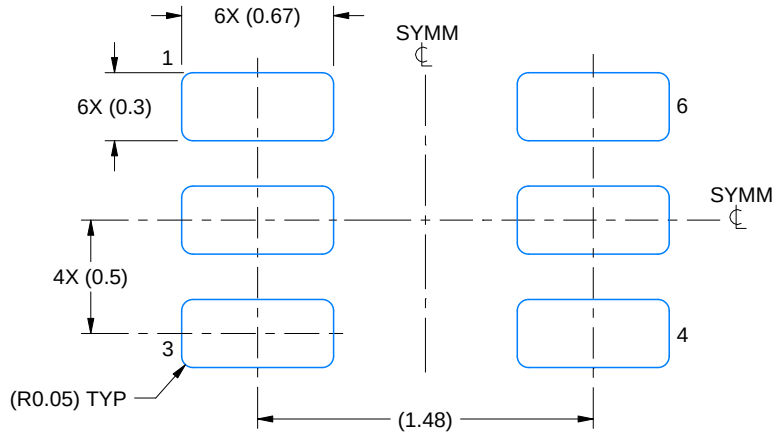
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. Reference JEDEC registration MO-293 Variation UAAD

EXAMPLE BOARD LAYOUT

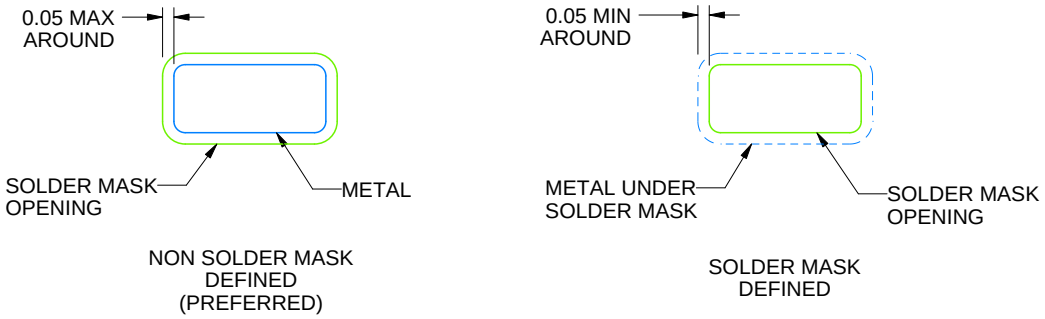
DRL0006A

SOT - 0.6 mm max height

PLASTIC SMALL OUTLINE



LAND PATTERN EXAMPLE
SCALE:30X



SOLDERMASK DETAILS

4223266/F 11/2024

NOTES: (continued)

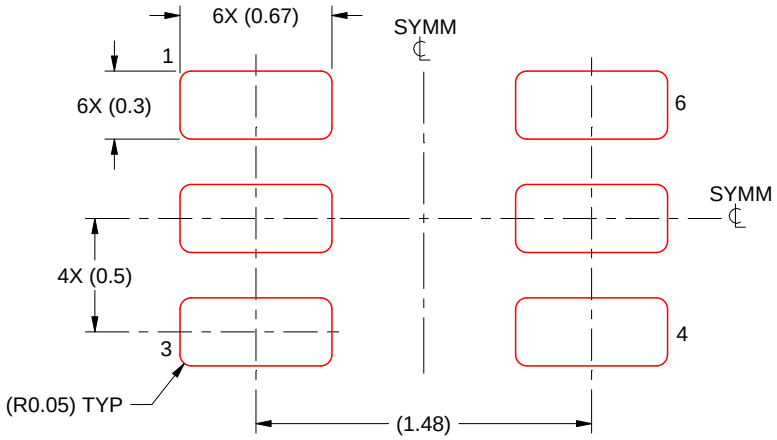
5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
7. Land pattern design aligns to IPC-610, Bottom Termination Component (BTC) solder joint inspection criteria.

EXAMPLE STENCIL DESIGN

DRL0006A

SOT - 0.6 mm max height

PLASTIC SMALL OUTLINE



SOLDER PASTE EXAMPLE
BASED ON 0.1 mm THICK STENCIL
SCALE:30X

4223266/F 11/2024

NOTES: (continued)

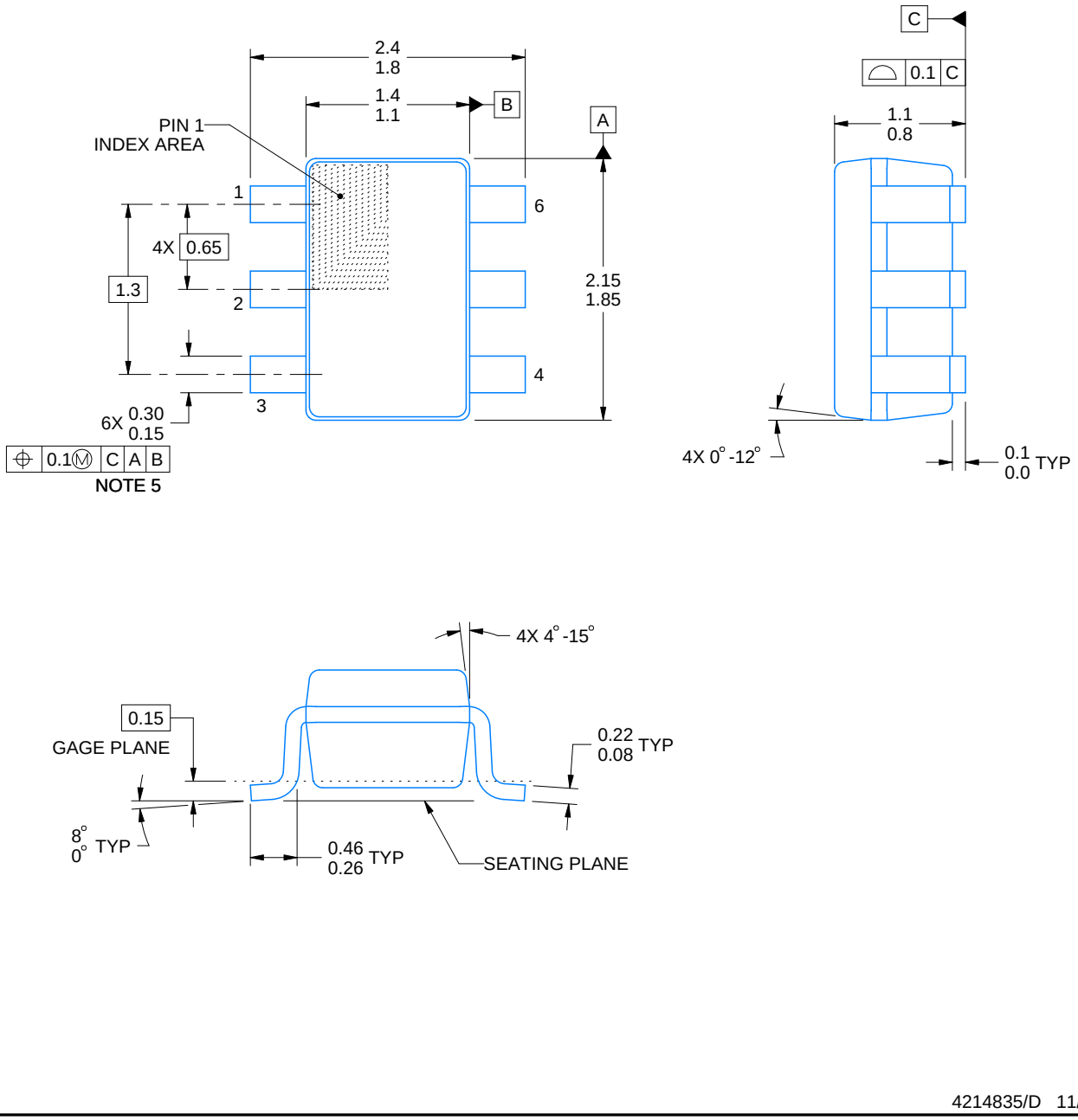
8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

PACKAGE OUTLINE

DCK0006A

SOT - 1.1 max height

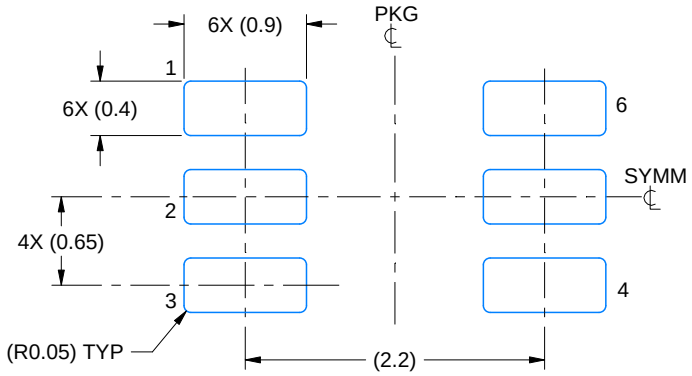
SMALL OUTLINE TRANSISTOR



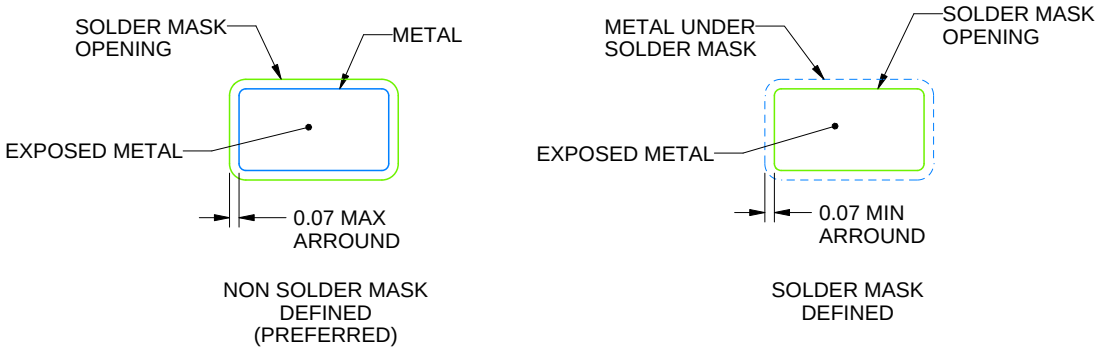
4214835/D 11/2024

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
4. Falls within JEDEC MO-203 variation AB.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:18X

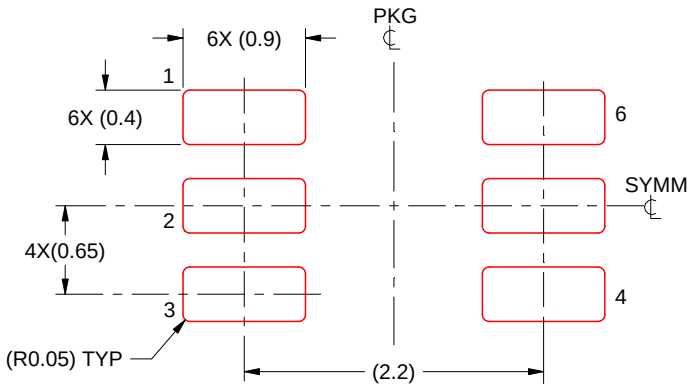


SOLDER MASK DETAILS

4214835/D 11/2024

NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 THICK STENCIL
SCALE:18X

4214835/D 11/2024

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

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